

# Characterization and Testbeam Analysis of irradiated Silicon n-in-p Pixel Detectors for the ATLAS Upgrades

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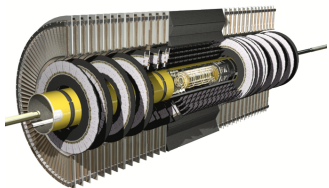
<sup>2</sup>MPI-Halbleiterlabor

<sup>3</sup>CERN-PH

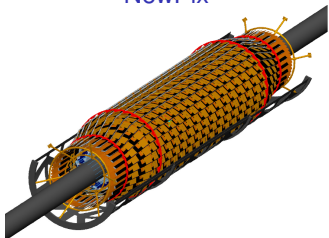
18th RD50 Workshop  
Liverpool May 2011



# Future of ATLAS and LHC



NewPix



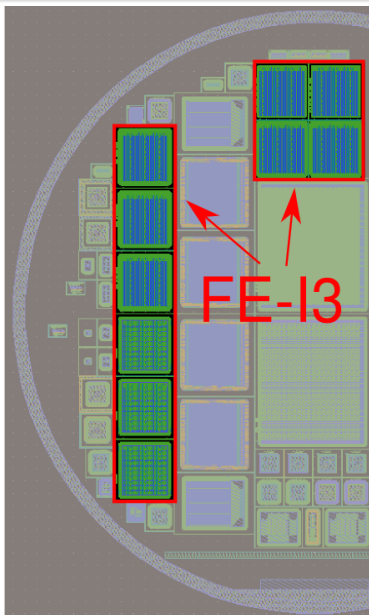
## Keystones for upgrade

- Twofold Upgrade:
  - IBL  $\sim 2013/4$
  - HL-HC/NewPix  $\sim 2018$  (Under discussion)
- Luminosity:  $(2 - 3) \cdot 10^{34} - 10^{35} / (\text{cm}^2\text{s})$
- $\Rightarrow$  radiation dose:  $\phi_{\text{eq}} \approx 10^{15} - 10^{16} \text{ n}_{\text{eq}}/\text{cm}^2$

## NewPix Specs

- New front-end chip (FE-I4/5?) and new sensor design ( $250 \mu\text{m} \times 50 \mu\text{m}$ )  $\rightarrow$  Improved vertex resolution (b-tagging!)
- Present workhorse for R&D: ATLAS front-end chip (FE-I3:  $400 \mu\text{m} \times 50 \mu\text{m}$ )
- Sensor-technology not yet fixed: n-in-p is an excellent candidate for this large volumes.
  - Only one side needs processing  $\rightarrow$  reduced cost.
  - Radiation hardness compatible with n-in-n

# CiS-Production (n-in-p Batch)



18 Fz n-in-p wafers, 285  $\mu\text{m}$  thick  
delivered by CiS

10 $\times$ FE-I3: Single Chip Modules (SCM) with  
different GR and isolation schemes:

- 2 $\times$  8 GRs, homogeneous p-spray
- 2 $\times$  15 GRs, homogeneous p-spray
- 3 $\times$  Standard (19) GR, homogeneous p-spray
- 3 $\times$  Standard (19) GR, moderated p-spray

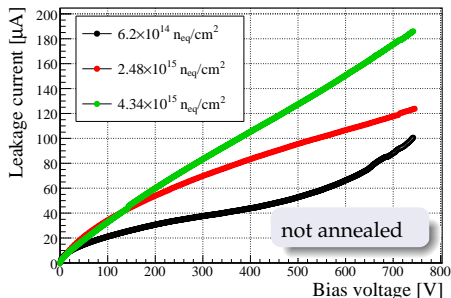
By now 19 SCMs were built by IZM.  
Assembly on Bonn-boards and wire-bonding  
done in Bonn.

—Thanks!

# Irradiations

- **CERN protons at 24 GeV**
  - 1 sensor at  $6.2 \cdot 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 sensor at  $2.5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 sensor at  $4.4 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 SCM at  $2.8 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 SCM at  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
- **Karlsruhe protons at 25 MeV**
  - 1 SCM at  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

- **Ljubljana neutrons**
  - 1 SCM at  $2 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 SCM at  $3 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 SCM at  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
  - 1 SCM at  $10^{16} \text{ n}_{\text{eq}}/\text{cm}^2$  (ongoing)
- **Ljubljana neutrons + Karlsruhe protons at 25 MeV**
  - 1 SCM at  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2 + 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

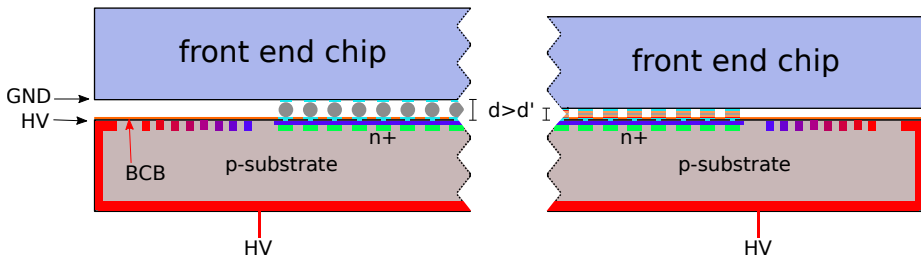


For the irradiations we thank:

M. Glaser at CERN-PS  
 A. Dierlamm and the Helmholtz Alliance at KIT  
 V. Cindro in Ljubljana

# HV Stability - BCB

n-in-p: HV is on sensor side facing the chip  $\rightarrow$  danger of sparks!



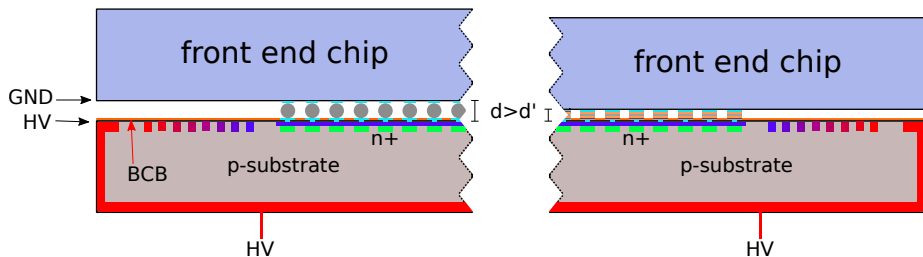
Alternative interconnection technologies like SLID (Solid Liquid Interdiffusion; Cu+Sn pad) further reduce the distance!

**Solution:** Cover sensor with a thin layer of BCB (Benzo Cyclo Butene)

HV-stability observed @ 1000 V over several hours.

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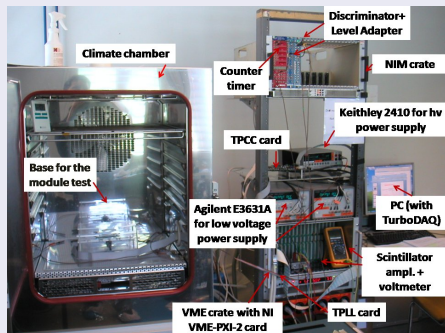
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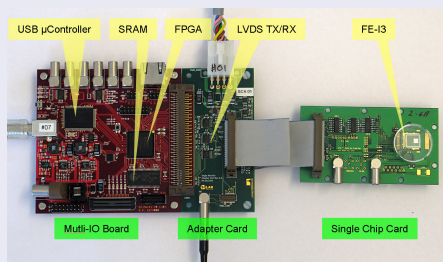
# DAQ-Systems

## TurboDAQ



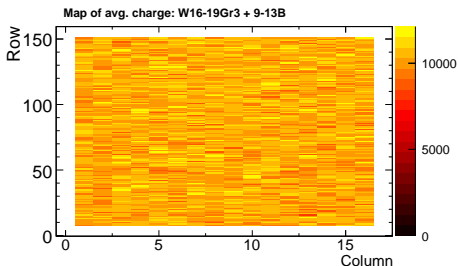
- PC-to-VME interface
- CERN ATLAS Pixel Group setup

## USBix



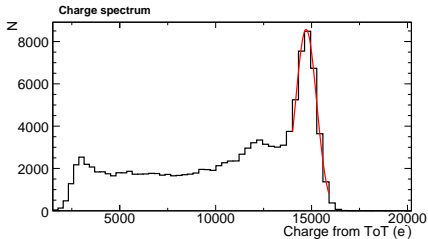
- Modular system with USB interface
- Readout based on ATLAS software  $\rightarrow$  reusability

# $^{241}\text{Am}$ Measurements



## Setup:

- $^{241}\text{Am}$  source illuminating full detector
- Internal FE-I3 trigger
- Not irradiated
- TurboDAQ setup



## Result:

- Nice resolution of spectrum
- 59.5 keV  $\gamma$ -line seen at  $14.7 \text{ ke}^-$
- 10–15 % uncertainty from TOT-calibration

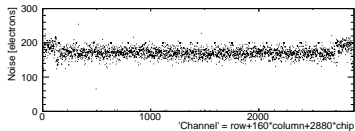
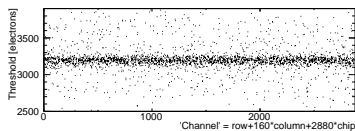
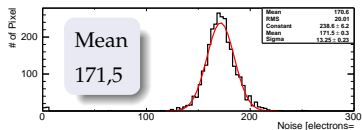
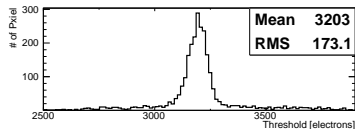
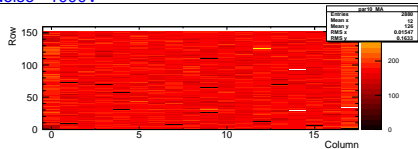
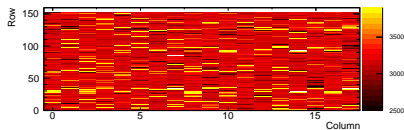


# Tuning for Highly Irradiated Sample

Good tuning for the  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  sample at  $-60^\circ\text{C}$

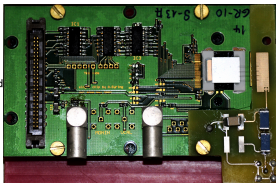
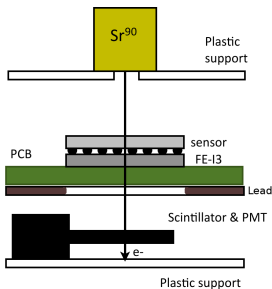
Threshold - 1000V

Noise - 1000V

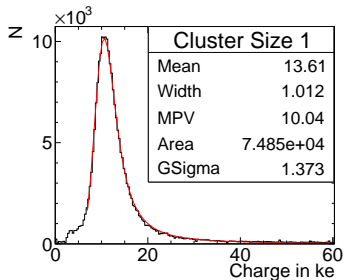
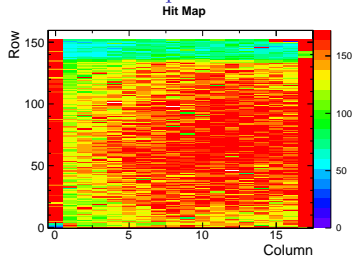


# $^{90}\text{Sr}$ -Measurement

- $^{90}\text{Sr}$  source is used for charge collection measurement.
- External trigger via scintillator.
- Measurement done for fluences up to  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$ , 1000 V
- Events with two independent clusters are discarded  $\rightarrow$  removes noise



$5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$ , 1000 V

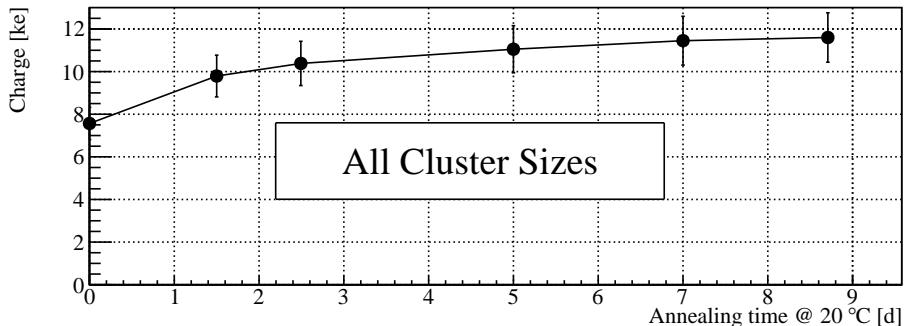


# Proton Irradiated Sample - Annealing

Proton irradiation at KIT possible with SCM mounted on card → no/minimal annealing due to handling (gluing, bonding) after irradiation.

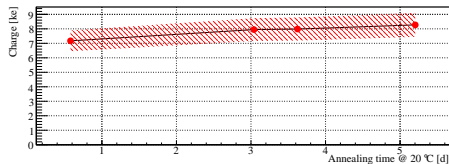
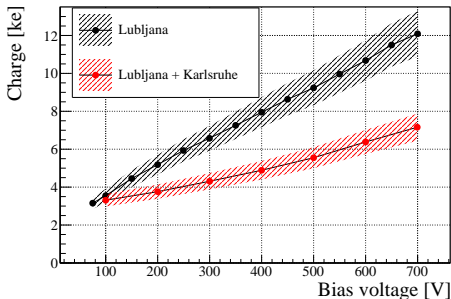
One SCM was irradiated to  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  with  $E = 25 \text{ MeV p.}$  in Karlsruhe

Around 25 % of the collected charge recovers within 9 days at room temperature. As expected biggest effect in the beginning.



# Mixed irradiation

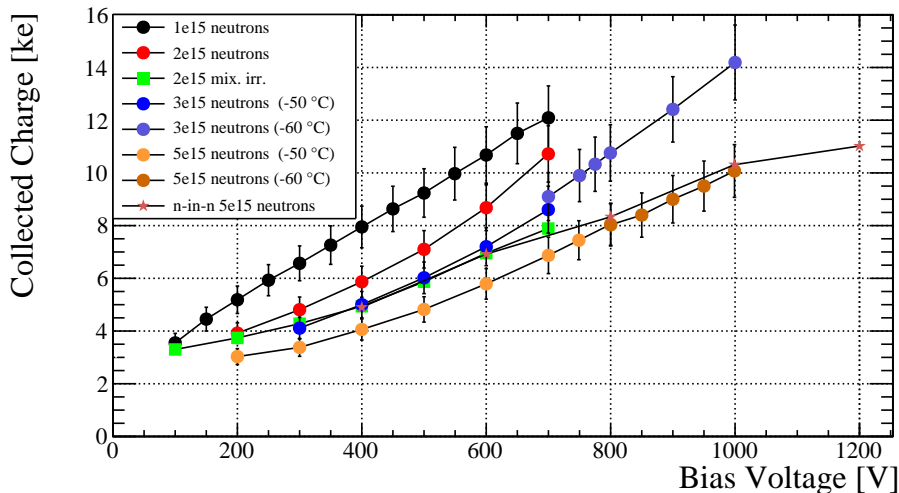
One SCM was irradiated 2x:  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  (LJ) +  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  (KA)



- Sufficient charge collection after irradiation
- Measurements at higher voltages limited by HV capabilities of Bonn-board
- Compared to not irradiated sensors the collected charge at 700 V is
  - ~65% after irradiation in Ljubljana
  - ~39% after both irradiations
- Low noise between 100 and 120 e<sup>-</sup>

Measurements done at -20 °C (Ljubljana) and -50 °C (Ljubljana + Karlsruhe)

# Collected Charge (Overview)

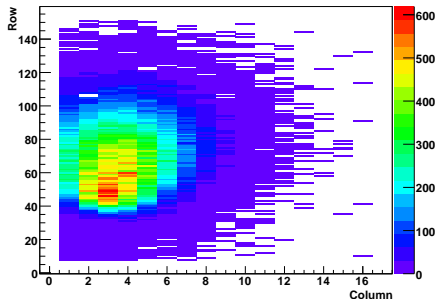


All neutron samples got annealing of around 2 days due to mounting back to cards after irradiation. Highest leakage currents  $\sim 5 \mu\text{A}$ . n-in-n sample measurements by A. Rummler.

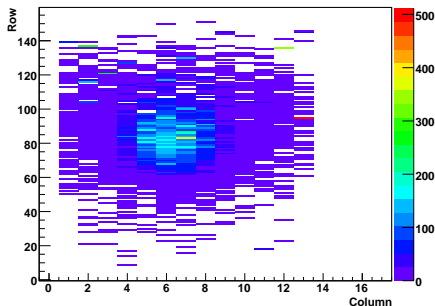
# PS irradiation

Temperature  $-20^{\circ}\text{C} \Rightarrow$  Only tested up to 200 V till now.

$2.8 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



$5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

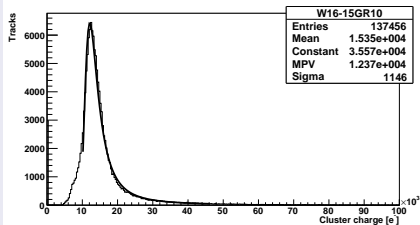


Tuning worked fine, no dead pixels in collimator region. CCE measurements need cooler environment, provided by new climate chamber.

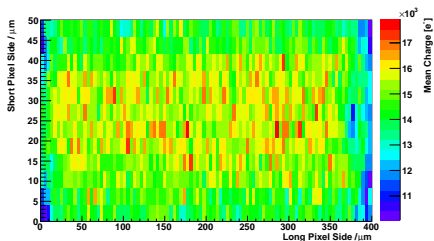
# Proton Irradiated Sample - Testbeam results (prelim.)

- Run at 500V with a fluence of  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$
- Collected charge in agreement with lab measurements
- Good charge collection in the whole sensor area

## Collected charge



## Collected charge by track position



**Testbeam-Group July/Oct 2010:** M. Beimforde, M. Benoit, M. Bomben, G. Calderini, Ch. Gallrapp, M. George, S. Gibson, S. Grinstein, Z. Janoska, J. Jentsch, O. Jinnouchi, T. Kishida, A. La Rosa, V. Libov, A. Macchiolo, G. Marchiori, D. Muenstermann, R. Nagai, G. Piacquadio, B. Ristic, I. Rubinskiy, A. Rummler, D. Sutherland, Y. Takubo, G. Troska, S. Tsiskaridze, I. Tsurin, Y. Unno, P. Weigell, J. Weingarten, T. Wittig

# Summary and Plans

## Summary

- SCM irradiated up to  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  were measured up to 1000 V.
- Stable operation at 1000 V for several hours.
- Charge collection for voltages higher than 600 V well above threshold (3.2 ke) up to  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$ .

## Plans

- Finish measurements for CERN PS irradiated samples.
- Extend fluence to  $10^{16} \text{ n}_{\text{eq}}/\text{cm}^2$ , sample irradiated last week in Ljubljana.
- Put  $5 \cdot 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$  and  $10^{16} \text{ n}_{\text{eq}}/\text{cm}^2$  sample into testbeam.
- Extend the testbeam analysis.
- Gamma source scans for irradiated samples.